



Integrated Device Technology, Inc.

FAST CMOS OCTAL D REGISTERS (3-STATE)

IDT54/74FCT374T/AT/CT/DT - 2374T/AT/CT

IDT54/74FCT534T/AT/CT

IDT54/74FCT574T/AT/CT/DT - 2574T/AT/CT

FEATURES:

• Common features:

- Low input and output leakage $\leq 1\mu A$ (max.)
- CMOS power levels
- True TTL input and output compatibility
 - $V_{OH} = 3.3V$ (typ.)
 - $V_{OL} = 0.3V$ (typ.)
- Meets or exceeds JEDEC standard 18 specifications
- Product available in Radiation Tolerant and Radiation Enhanced versions
- Military product compliant to MIL-STD-883, Class B and DESC listed (dual marked)
- Available in DIP, SOIC, SSOP, QSOP, CERPACK and LCC packages

• Features for FCT374T/FCT534T/FCT574T:

- Std., A, C and D speed grades
- High drive outputs (-15mA I_{OH} , 48mA I_{OL})

• Features for FCT2374T/FCT2574T:

- Std., A, and C speed grades
- Resistor outputs (-15mA I_{OH} , 12mA I_{OL} Com.)
(-12mA I_{OH} , 12mA I_{OL} Mil.)
- Reduced system switching noise

DESCRIPTION

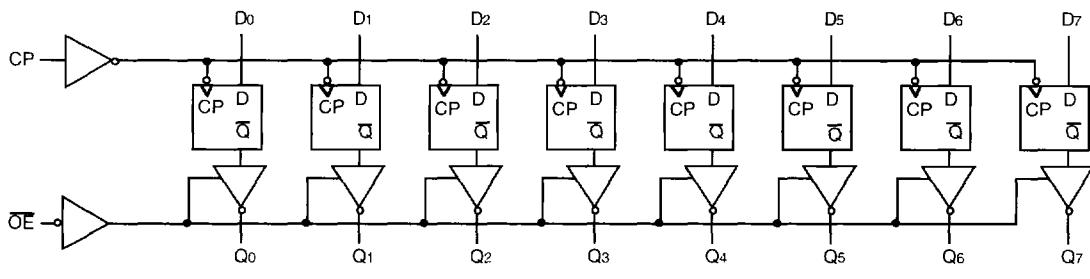
The FCT374T/FCT2374T, FCT534T and FCT574T/FCT2574T are 8-bit registers built using an advanced dual metal CMOS technology. These registers consist of eight D-type flip-flops with a buffered common clock and buffered 3-state output control. When the output enable (\overline{OE}) input is LOW, the eight outputs are enabled. When the \overline{OE} input is HIGH, the outputs are in the high-impedance state.

Input data meeting the set-up and hold time requirements of the D inputs is transferred to the Q outputs on the LOW-to-HIGH transition of the clock input.

The FCT2374T and FCT2574T have balanced output drive with current limiting resistors. This offers low ground bounce, minimal undershoot and controlled output fall times-reducing the need for external series terminating resistors. FCT2xxxT parts are plug-in replacements for FCTxxxT parts.

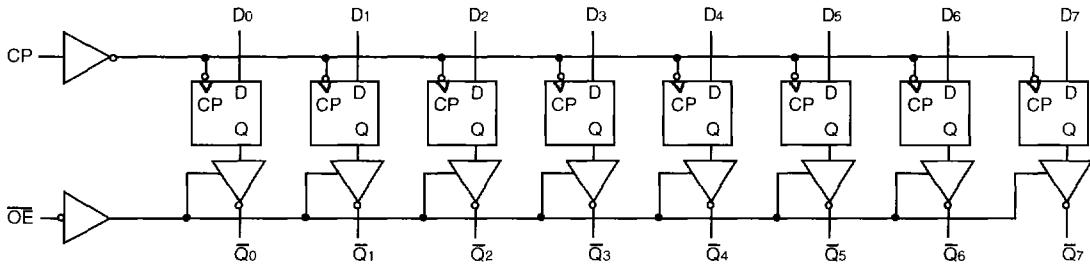
FUNCTIONAL BLOCK DIAGRAM FCT374/FCT2374T AND FCT574/FCT2574T

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FUNCTIONAL BLOCK DIAGRAM FCT534T



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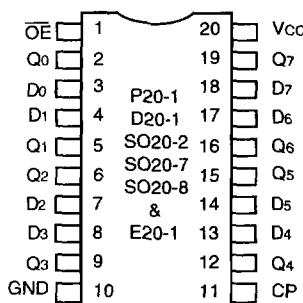
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MILITARY AND COMMERCIAL TEMPERATURE RANGES

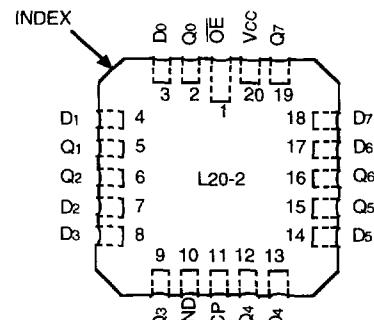
JUNE 1996

PIN CONFIGURATIONS

IDT54/74FCT374T



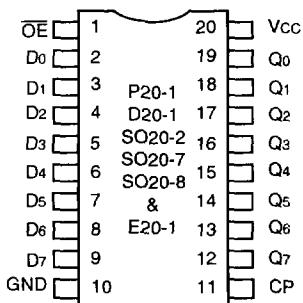
DIP/SOIC/SSOP/QSOP/CERPACK
TOP VIEW



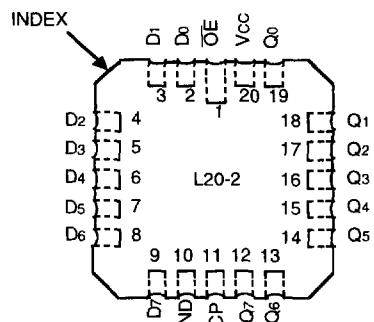
LCC
TOP VIEW

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IDT54/74FCT574T



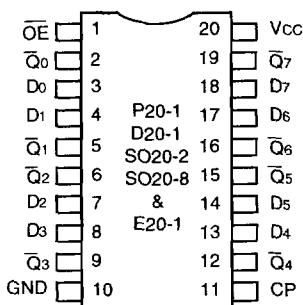
DIP/SOIC/SSOP/QSOP/CERPACK
TOP VIEW



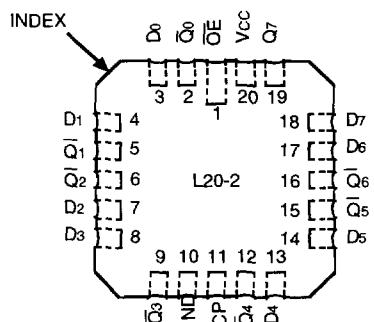
LCC
TOP VIEW

2569 drw 04

IDT54/74FCT534T



DIP/SOIC/QSOP/CERPACK
TOP VIEW



LCC
TOP VIEW

2569 drw 05

PIN DESCRIPTION

Pin Names	Description
D _N	D flip-flop data inputs
CP	Clock Pulse for the register. Enters data on LOW-to-HIGH transition.
Q _N	3-state outputs, (true)
Q̄ _N	3-state outputs, (inverted)
OE	Active LOW 3-state Output Enable input

2569 tbl 01

FUNCTION TABLE⁽¹⁾

Function	Inputs			534		374/574	
				Outputs	Internal	Outputs	Internal
	OE	CP	D _N	Q _N	Q _N	Q _N	Q̄ _N
Hi-Z	H	L	X	Z	NC	Z	NC
	H	H	X	Z	NC	Z	NC
LOAD REGISTER	L	↑	L	H	L	L	H
	L	↑	H	L	H	H	L
	H	↑	L	Z	L	Z	H
	H	↑	H	Z	H	Z	L

2569 tbl 02

NOTE:

1. H = HIGH Voltage Level
- L = LOW Voltage Level
- X = Don't Care
- Z = High Impedance
- NC = No Change
- ↑ = LOW-to-HIGH transition

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ABSOLUTE MAXIMUM RATINGS⁽¹⁾

Symbol	Rating	Commercial	Military	Unit
VTERM ⁽²⁾	Terminal Voltage with Respect to GND	-0.5 to +7.0	-0.5 to +7.0	V
VTERM ⁽³⁾	Terminal Voltage with Respect to GND	-0.5 to Vcc +0.5	-0.5 to Vcc +0.5	V
TA	Operating Temperature	0 to +70	-55 to +125	°C
TBIAS	Temperature Under Bias	-55 to +125	-65 to +135	°C
TSTG	Storage Temperature	-55 to +125	-65 to +150	°C
Pr	Power Dissipation	0.5	0.5	W
Iout	DC Output Current	-60 to +120	-60 to +120	mA

2569 Ink 03

NOTES:

1. Stresses greater than those listed under ABSOLUTE MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability. No terminal voltage may exceed Vcc by +0.5V unless otherwise noted.
2. Input and Vcc terminals only.
3. Outputs and I/O terminals only.

CAPACITANCE (TA = +25°C, f = 1.0MHz)

Symbol	Parameter ⁽¹⁾	Conditions	Typ.	Max.	Unit
C _{IN}	Input Capacitance	V _{IN} = 0V	6	10	pF
C _{OUT}	Output Capacitance	V _{OUT} = 0V	8	12	pF

2569 Ink 04

1. This parameter is measured at characterization but not tested.

DC ELECTRICAL CHARACTERISTICS OVER OPERATING RANGE

Following Conditions Apply Unless Otherwise Specified:

Commercial: TA = 0°C to +70°C, Vcc = 5.0V ± 5%; Military: TA = -55°C to +125°C, Vcc = 5.0V ± 10%

Symbol	Parameter	Test Conditions ⁽¹⁾		Min.	Typ. ⁽²⁾	Max.	Unit
V _{IH}	Input HIGH Level	Guaranteed Logic HIGH Level		2.0	—	—	V
V _{IL}	Input LOW Level	Guaranteed Logic LOW Level		—	—	0.8	V
I _{IH}	Input HIGH Current ⁽⁴⁾	Vcc = Max.	V _I = 2.7V	—	—	±1	μA
			V _I = 0.5V	—	—	±1	
I _{OZH}	High Impedance Output Current	Vcc = Max. (3-State Output pins) ⁽⁴⁾	V _O = 2.7V	—	—	±1	μA
I _{OZL}			V _O = 0.5V	—	—	±1	
I _I	Input HIGH Current ⁽⁴⁾	Vcc = Max., V _I = Vcc (Max.)	—	—	—	±1	μA
V _{IK}	Clamp Diode Voltage	Vcc = Min., I _{IN} = -18mA	—	—	-0.7	-1.2	V
V _H	Input Hysteresis	—	—	—	200	—	mV
I _{CC}	Quiescent Power Supply Current	Vcc = Max., V _{IN} = GND or Vcc	—	0.01	1	—	mA

2569 Ink 05

OUTPUT DRIVE CHARACTERISTICS FOR FCT374T/534T/574T

Symbol	Parameter	Test Conditions ⁽¹⁾		Min.	Typ. ⁽²⁾	Max.	Unit
V _{OH}	Output HIGH Voltage	Vcc = Min. V _{IN} = V _{IH} or V _{IL}	I _{OH} = -6mA MIL. I _{OH} = -8mA COM'L.	2.4	3.3	—	V
			I _{OH} = -12mA MIL. I _{OH} = -15mA COM'L.	2.0	3.0	—	V
V _{OL}	Output LOW Voltage	Vcc = Min. V _{IN} = V _{IH} or V _{IL}	I _{OL} = 32mA MIL. I _{OL} = 48mA COM'L.	—	0.3	0.5	V
I _{OS}	Short Circuit Current	Vcc = Max.. Vo = GND ⁽³⁾	—	-60	-120	-225	mA

2569 Ink 06

OUTPUT DRIVE CHARACTERISTICS FOR FCT2374T/2574T

Symbol	Parameter	Test Conditions ⁽¹⁾		Min.	Typ. ⁽²⁾	Max.	Unit
I _{ODL}	Output LOW Current	Vcc = 5V, V _{IN} = V _{IH} or V _{IL} , V _{OUT} = 1.5V ⁽³⁾	—	16	48	—	mA
I _{ODH}	Output HIGH Current	Vcc = 5V, V _{IN} = V _{IH} or V _{IL} , V _{OUT} = 1.5V ⁽³⁾	—	-16	-48	—	mA
V _{OH}	Output HIGH Voltage	Vcc = Min. V _{IN} = V _{IH} or V _{IL}	I _{OH} = -12mA MIL. I _{OH} = -15mA COM'L.	2.4	3.3	—	V
V _{OL}	Output LOW Voltage	Vcc = Min. V _{IN} = V _{IH} or V _{IL}	I _{OL} = 12mA	—	0.3	0.50	V

2569 Ink 07

NOTES:

1. For conditions shown as Max. or Min., use appropriate value specified under Electrical Characteristics for the applicable device type.
2. Typical values are at Vcc = 5.0V, +25°C ambient.
3. Not more than one output should be shorted at one time. Duration of the short circuit test should not exceed one second.
4. The test limit for this parameter is ±5μA at TA = -55°C.

POWER SUPPLY CHARACTERISTICS

Symbol	Parameter	Test Conditions ⁽¹⁾			Min.	Typ. ⁽²⁾	Max.	Unit
ΔI_{CC}	Quiescent Power Supply Current TTL Inputs HIGH	V _{CC} = Max. V _{IN} = 3.4V ⁽³⁾			—	0.5	2.0	mA
I_{CCD}	Dynamic Power Supply Current ⁽⁴⁾	V _{CC} = Max. Outputs Open \overline{OE} = GND One Input Toggling 50% Duty Cycle	V _{IN} = V _{CC} V _{IN} = GND	FCT _{xxxT}	—	0.15	0.25	mA/ MHz
				FCT2 _{xxxT}	—	0.06	0.12	
I_C	Total Power Supply Current ⁽⁶⁾	V _{CC} = Max. Outputs Open $f_{CP} = 10\text{MHz}$ 50% Duty Cycle \overline{OE} = GND $f_i = 5\text{MHz}$ 50% Duty Cycle One Bit Toggling	V _{IN} = V _{CC} V _{IN} = GND	FCT _{xxxT}	—	1.5	3.5	mA
				FCT2 _{xxxT}	—	0.6	2.2	
			V _{IN} = 3.4 V _{IN} = GND	FCT _{xxxT}	—	2.0	5.5	
				FCT2 _{xxxT}	—	1.1	4.2	
		V _{CC} = Max. Outputs Open $f_{CP} = 10\text{MHz}$ 50% Duty Cycle \overline{OE} = GND Eight Bits Toggling $f_i = 2.5\text{MHz}$ 50% Duty Cycle	V _{IN} = V _{CC} V _{IN} = GND	FCT _{xxxT}	—	3.8	7.3 ⁽⁵⁾	
				FCT2 _{xxxT}	—	1.5	4.0 ⁽⁵⁾	
			V _{IN} = 3.4 V _{IN} = GND	FCT _{xxxT}	—	6.0	16.3 ⁽⁵⁾	
				FCT2 _{xxxT}	—	3.8	13.0 ⁽⁶⁾	

NOTES:

1. For conditions shown as Max. or Min., use appropriate value specified under Electrical Characteristics for the applicable device type.

2. Typical values are at V_{CC} = 5.0V, +25°C ambient.

3. Per TTL driven input (V_{IN} = 3.4V). All other inputs at V_{CC} or GND.

4. This parameter is not directly testable, but is derived for use in Total Power Supply Calculations.

5. Values for these conditions are examples of the I_{CC} formula. These limits are guaranteed but not tested.

6. $I_C = I_{QUIESCENT} + I_{INPUTS} + I_{DYNAMIC}$

$$I_{CC} = I_{CC} + \Delta I_{CC} D_N T + I_{CCD} (f_{CP}/2 + f_{NI})$$

I_{CC} = Quiescent Current

ΔI_{CC} = Power Supply Current for a TTL High Input (V_{IN} = 3.4V)

D_H = Duty Cycle for TTL Inputs High

N_T = Number of TTL Inputs at D_H

I_{CCD} = Dynamic Current Caused by an Input Transition Pair (HLH or LHL)

f_{CP} = Clock Frequency for Register Devices (Zero for Non-Register Devices)

f_i = Input Frequency

N_i = Number of Inputs at f_i

All currents are in millamps and all frequencies are in megahertz.

SWITCHING CHARACTERISTICS OVER OPERATING RANGE

Symbol	Parameter	Conditions ⁽¹⁾	FCT374T/534T/574T				FCT374AT/534AT/574AT				Unit	
			FCT2374T/2574T		FCT2374AT/2574AT							
			Com'l.		Mil.		Com'l.		Mil.			
			Min. ⁽²⁾	Max.	Min. ⁽²⁾	Max.	Min. ⁽²⁾	Max.	Min. ⁽²⁾	Max.		
tPLH	Propagation Delay CP to Q _N ⁽³⁾	CL = 50pF RL = 500Ω	2.0	10.0	2.0	11.0	2.0	6.5	2.0	7.2	ns	
tPHL	Output Enable Time		1.5	12.5	1.5	14.0	1.5	6.5	1.5	7.5	ns	
tPZH	Output Disable Time		1.5	8.0	1.5	8.0	1.5	5.5	1.5	6.5	ns	
tPZL	Set-up Time HIGH or LOW, DN to CP		2.0	—	2.0	—	2.0	—	2.0	—	ns	
t _H	Hold Time HIGH or LOW, DN to CP		1.5	—	1.5	—	1.5	—	1.5	—	ns	
t _W	CP Pulse Width HIGH or LOW		7.0	—	7.0	—	5.0	—	6.0	—	ns	

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Symbol	Parameter	Conditions ⁽¹⁾	FCT374CT/534CT/574CT				FCT374DT/574DT				Unit	
			FCT2374CT/2574CT		FCT2374DT/2574DT							
			Com'l.		Mil.		Com'l.		Mil.			
			Min. ⁽²⁾	Max.	Min. ⁽²⁾	Max.	Min. ⁽²⁾	Max.	Min. ⁽²⁾	Max.		
tPLH	Propagation Delay CP to Q _N ⁽³⁾	CL = 50pF RL = 500Ω	2.0	5.2	2.0	6.2	2.0	4.2	—	—	ns	
tPHL	Output Enable Time		1.5	5.5	1.5	6.2	1.5	4.8	—	—	ns	
tPZH	Output Disable Time		1.5	5.0	1.5	5.7	1.5	4.0	—	—	ns	
tPZL	Set-up Time HIGH or LOW, DN to CP		2.0	—	2.0	—	2.0	—	—	—	ns	
t _H	Hold Time HIGH or LOW, DN to CP		1.5	—	1.5	—	1.0	—	—	—	ns	
t _W	CP Pulse Width HIGH or LOW ⁽⁴⁾		5.0	—	6.0	—	3.0	—	—	—	ns	

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NOTES:

1. See test circuit and waveforms.
2. Minimum limits are guaranteed but not tested on Propagation Delays.
3. On for FCT374/2374T and FCT574/2574T, $\bar{O}n$ for FCT534T.
4. This parameter is guaranteed but not tested.



Integrated Device Technology, Inc.

FAST CMOS OCTAL D FLIP-FLOP WITH CLOCK ENABLE

IDT54/74FCT377T/AT/CT/DT

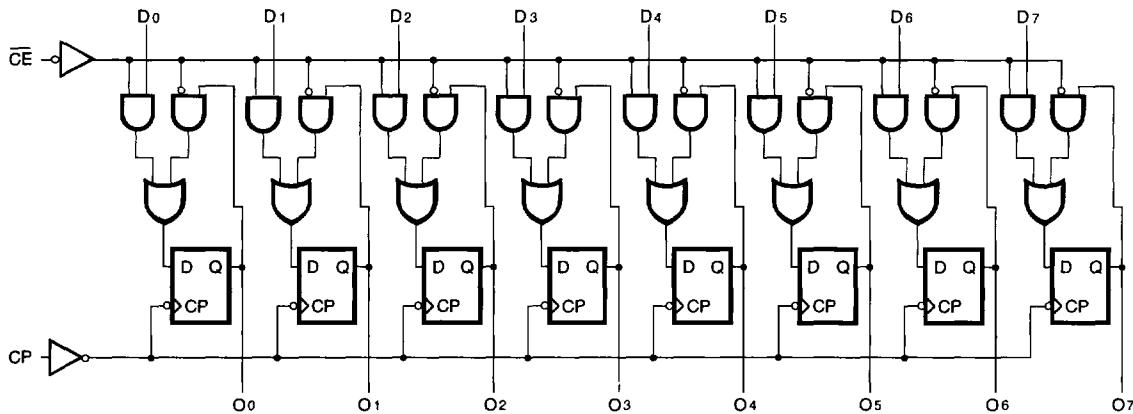
FEATURES:

- Std., A, C and D speed grades
- Low input and output leakage $\leq 1\mu\text{A}$ (max.)
- CMOS power levels
- True TTL input and output compatibility
 - $V_{OH} = 3.3\text{V}$ (typ.)
 - $V_{OL} = 0.3\text{V}$ (typ.)
- High drive outputs (-15mA I_{OH} , 48mA I_{OL})
- Power off disable outputs permit "live insertion"
- Meets or exceeds JEDEC standard 18 specifications
- Product available in Radiation Tolerant and Radiation Enhanced versions
- Military product compliant to MIL-STD-883, Class B and DESC listed (dual marked)
- Available in DIP, SOIC, QSOP, CERPACK and LCC packages

DESCRIPTION:

The IDT54/74FCT377T/AT/CT/DT are octal D flip-flops built using an advanced dual metal CMOS technology. The IDT54/74FCT377T/AT/CT/DT have eight edge-triggered, D-type flip-flops with individual D inputs and Q outputs. The common buffered Clock (CP) input loads all flip-flops simultaneously when the Clock Enable (\overline{CE}) is LOW. The register is fully edge-triggered. The state of each D input, one set-up time before the LOW-to-HIGH clock transition, is transferred to the corresponding flip-flop's Q output. The \overline{CE} input must be stable only one set-up time prior to the LOW-to-HIGH transition for predictable operation.

FUNCTIONAL BLOCK DIAGRAM



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MILITARY AND COMMERCIAL TEMPERATURE RANGES

JUNE 1996

ORDERING INFORMATION

IDT	XX	FCT	X	XXXX	X	Package	X	Process
							Blank	Commercial
							B	MIL-STD-883, Class B
						P	Plastic DIP	
						D	CERDIP	
						SO	Small Outline IC	
						L	Leadless Chip Carrier	
						E	CERPACK	
						PY	Shrink Small Outline Package	
						Q	Quarter-size Small Outline Package	
					374T		Non-Inverting Octal D Register	
					574T		Non-Inverting Octal D Register	
					534T		Inverting Octal D Register	
				374AT				
				574AT				
				534AT				
				374CT				
				574CT				
				534CT				
				374DT				
				574DT				
					Blank		High Drive	
					2		Balanced Drive	
						54	-55°C to +125°C	
						74	0°C to +70°C	

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